

BD137**1.5 A, 60 V NPN Power Bipolar Junction Transistor****Product Overview**

For complete documentation, see the data sheet.

This series of plastic, medium-power NPN power bipolar junction transistors are designed for use as audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

Features

- Minimum DC Current Gain - $h_{FE} = 40$ @ $I_C = 0.15$ A
- BD135, BD137, BD139 are complementary with BD136, BD138, BD140
- These are Pb-Free Devices